

Data Sheet

Description

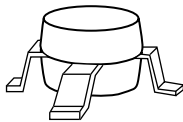
The MSA-1105 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for high dynamic range in either 50 Ω or 75 Ω systems by combining low noise figure with high IP_3 . Typical applications include narrow and broadband linear amplifiers in commercial and industrial systems.

The MSA-series is fabricated using Avago's 10 GHz f_T , 25 GHz f_{MAX} silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

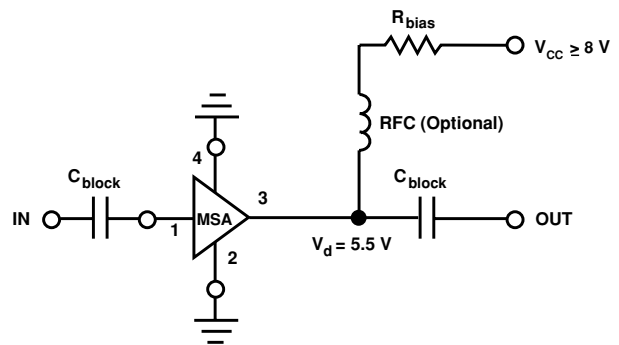
Features

- High Dynamic Range Cascadable 50 Ω or 75 Ω Gain Block
- 3 dB Bandwidth: 50 MHz to 1.3 GHz
- 17.5 dBm Typical $P_{1\text{ dB}}$ at 0.5 GHz
- 3.6 dB Typical Noise Figure at 0.5 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

05 Plastic Package



Typical Biasing Configuration



MSA-1105 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	80 mA
Power Dissipation ^[2,3]	550 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	–65 to 150°C

Thermal Resistance^[2]:

$$\theta_{jc} = 125^{\circ}\text{C/W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{\text{CASE}} = 25^{\circ}\text{C}$.
3. Derate at 8 mW/°C for $T_C > 124^{\circ}\text{C}$.

Electrical Specifications^[1], $T_A = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_d = 60 \text{ mA}$, $Z_0 = 50 \Omega$	Units	Min.	Typ.	Max.
G_p	Power Gain ($ S_{21} ^2$)	$f = 0.05 \text{ GHz}$			12.7
		$f = 0.5 \text{ GHz}$	10.0		12.0
		$f = 1.0 \text{ GHz}$			10.5
ΔG_p	Gain Flatness	$f = 0.1 \text{ to } 1.0 \text{ GHz}$		± 1.0	
$f_{3 \text{ dB}}$	3 dB Bandwidth ^[2]			1.3	
VSWR	Input VSWR	$f = 0.1 \text{ to } 1.0 \text{ GHz}$		1.5:1	
	Output VSWR	$f = 0.1 \text{ to } 1.0 \text{ GHz}$		1.7:1	
NF	50 Ω Noise Figure	$f = 0.5 \text{ GHz}$		3.6	
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression	$f = 0.5 \text{ GHz}$		17.5	
IP_3	Third Order Intercept Point	$f = 0.5 \text{ GHz}$		30.0	
t_D	Group Delay	$f = 0.5 \text{ GHz}$		200	
V_d	Device Voltage	V	4.4	5.5	6.6
dV/dT	Device Voltage Temperature Coefficient	mV/°C		–8.0	

Notes:

1. The recommended operating current range for this device is 40 to 70 mA.
Typical performance as a function of current is on the following page.
2. Referenced from 50 MHz gain (GP).

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-1105-STR	10	Bulk
MSA-1105-STRG	100	Bulk
MSA-1105-TR1	500	7" Reel
MSA-1105-TR1G	500	7" Reel
MSA-1105-TR2	1500	13" Reel
MSA-1105-TR2G	1500	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

MSA-1105 Typical Scattering Parameters ($Z_0 = 50 \Omega$, $T_A = 25^\circ\text{C}$, $I_d = 60 \text{ mA}$)

Freq. GHz	S_{11}			S_{21}			S_{12}		S_{22}		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
.0005	.80	-17	19.0	8.94	171	-26.0	.050	51	.81	-16	0.53
.005	.26	-62	13.9	4.98	163	-16.8	.144	15	.26	-64	0.93
.025	.07	-48	12.8	4.36	174	-16.4	.151	4	.08	-52	1.08
.050	.06	-38	12.7	4.33	174	-16.3	.153	2	.06	-48	1.08
.100	.05	-41	12.7	4.31	170	-16.4	.152	3	.06	-52	1.09
.200	.06	-58	12.6	4.26	162	-16.2	.155	5	.08	-73	1.08
.300	.07	-74	12.4	4.19	154	-16.1	.157	7	.10	-91	1.07
.400	.09	-91	12.2	4.10	146	-15.8	.163	8	.12	-105	1.06
.500	.10	-105	12.0	4.00	138	-15.6	.166	8	.14	-116	1.05
.600	.11	-116	11.8	3.88	131	-15.4	.171	10	.17	-126	1.04
.700	.13	-128	11.5	3.76	123	-15.0	.178	11	.18	-135	1.03
.800	.15	-136	11.2	3.63	116	-14.7	.184	11	.21	-144	1.01
.900	.16	-145	10.9	3.49	109	-15.5	.188	11	.22	-151	1.01
1.000	.18	-152	10.5	3.37	102	-14.1	.197	11	.24	-159	1.00
1.500	.28	174	8.8	2.75	72	-13.2	.219	7	.31	170	1.00
2.000	.38	150	7.1	2.28	48	-12.1	.248	0	.34	151	0.99
2.500	.46	133	5.6	1.90	28	-11.9	.254	-4	.38	134	1.02
3.000	.53	118	4.2	1.62	11	-11.6	.262	-8	.40	122	1.04

Typical Performance, $T_A = 25^\circ\text{C}$, $Z_0 = 50 \Omega$

(unless otherwise noted)

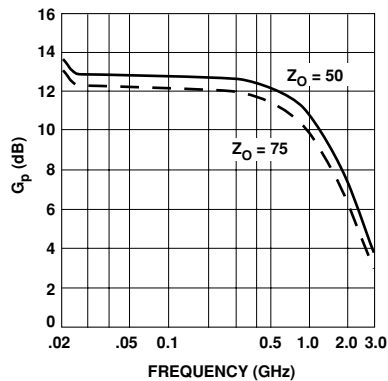


Figure 1. Typical Power Gain vs. Frequency, $I_d = 60 \text{ mA}$.

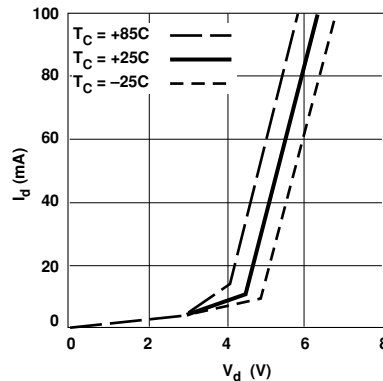


Figure 2. Device Current vs. Voltage.

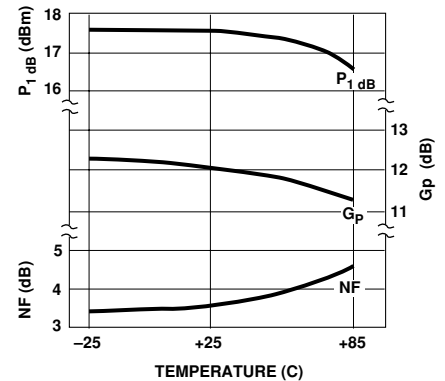


Figure 3. Output Power at 1 dB Gain Compression, Noise Figure and Power Gain vs. Case Temperature, $f = 0.5 \text{ GHz}$, $I_d = 60 \text{ mA}$.

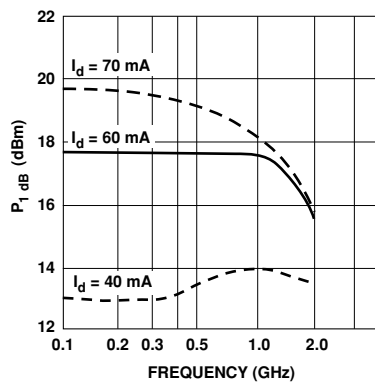


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

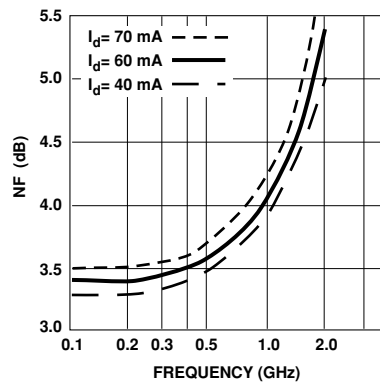
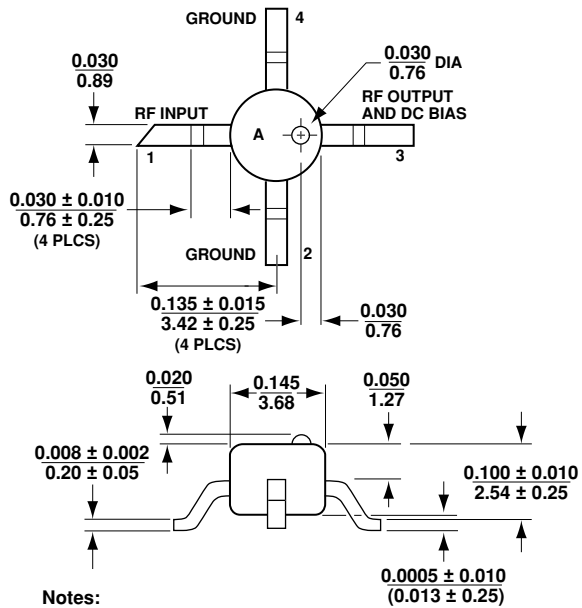


Figure 5. Noise Figure vs. Frequency.

05 Plastic Package Dimensions



Notes:

(unless otherwise specified)

1. Dimensions are $\frac{\text{in}}{\text{mm}}$
2. Tolerances
in .xxx = 0.005
mm .xx = 0.13

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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